

Effect of γ -irradiation on superconductivity in polycrystalline $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$

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Abstract

A bulk polycrystalline sample of $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ ($\delta \approx 0.1$) has been irradiated by γ -rays with ^{60}Co source. Non-monotonic behavior of T_c (defined as the temperature at which normal resistance is halved) with increasing irradiation dose Φ (up to about 220 MR) is observed: T_c decreases at low doses ($\Phi \leq 50$ MR) from initial value (≈ 93 K) by about 2 K and then rises, forming minimum. At highest doses ($\Phi \geq 120$ MR) T_c goes down again. The temperature width, δT_c , of resistive transition increases rather sharp with dose below 75 MR and somewhat drops at higher dose. We believe that this effect is revealed for the first time at γ -irradiation of high- T_c superconductor. The cross sections for the displacement of lattice atoms in YBCO by γ -rays due to the Compton process were calculated, and possible dpa values were estimated. The results obtained are discussed taking into account that sample studied is granular superconductor and, hence, the observed variations of superconducting properties should be connected primarily with the influence of γ -rays on intergrain Josephson coupling.

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I. INTRODUCTION

The influence of crystal lattice disorder on superconducting properties is one of the important problems of superconductivity. Theoretical insights into this field have been initiated by seminal Anderson's work [1]. In low- T_c superconductors (LTSCs) the disorder influence on critical temperature T_c is believed to be mainly due to dependences of density of states at the Fermi level $N(E_F)$, constant of electron-phonon interaction λ_{ep} or Coulomb interaction on disorder (see reviews in Refs. [2–4]). Many aspects of this problem are still not understood clearly. Things get much worse in the case of high- T_c superconductors (HTSCs) which are layered cuprates with perovskite-related structure. Really, it is hardly possible to consider the crystal-disorder effects in HTSCs quite properly in circumstances where the nature of superconducting pairing in these compounds is still controversial [5,6]. Notwithstanding this handicap, the crystal-lattice disorder effects in HTSCs have become topic of a large body of experimental and theoretical research [3,4]. The necessity of such type of studies is quite obvious from technological and fundamental points of view.

In HTSCs as well as in LTSCs the superconductivity involves pairs of electrons. Therefore, although the nature of superconducting paired state in the HTSCs is still obscure, it can be assumed that some features of the disorder influence should be common for both types of superconductors. This can be seen from the following consideration. The order parameter in the Ginzburg-Landau theory is written as $\Psi = \Delta \exp(i\varphi)$ where Δ is the amplitude and φ the phase of this parameter. The disorder can destroy the superconductivity either by reducing the amplitude of the order parameter or by destroying the phase coherence of superconducting electrons. The relative contribution of each of these mechanisms depends on the degree of inhomogeneity of the superconducting system [2]. The role of inhomogeneity can be judged by comparing the two characteristic lengths ξ_d and $\xi_{GL}(T)$, the first of which is characteristic scale of inhomogeneity associated with disorder and the second is the Ginzburg-Landau coherence length for dirty superconductors

$$\xi_{GL}(T) = \xi_{GL}(0)\epsilon^{-1/2}, \tag{1}$$

where $\xi_{GL}(0) = \pi D \hbar / 8 k T_c$ is the coherence length at $T = 0$, $D = v_F l / 3$ is the electron diffusion coefficient (v_F is Fermi velocity, l is electron elastic scattering length), $\epsilon = \ln(T_c/T)$. When $\xi_d \ll \xi_{GL}(T)$ (as for instance, in the case of the impurity or point defects of crystal lattice), the system behaves as homogeneous one, and disorder affects mainly the order parameter. In the opposite case, when $\xi_d \gtrsim \xi_{GL}(T)$, the system is inhomogeneous. An example of such system is granular metal consisting of metal grains separated by dielectric interlayer (ξ_d is grain size in this case). The reduction in the critical temperature T_c in inhomogeneous systems is largely due to the suppression of phase coherence between weakly coupled superconducting regions. Both mechanisms of the T_c reduction under disorder (reducing the amplitude of the order parameter and destroying the phase coherence of superconducting electrons) can operate simultaneously in real systems.

The HTSCs are usually characterized by low values of v_F and D as compared with that of LTSCs. Together with high T_c values, this should lead, according Eq. (1), to exceptionally short superconducting coherence length. Indeed, it was found, for example, in $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ that $\xi_{GL}(0)$ is about $\xi_{ab} \approx 1.4$ nm and $\xi_c \approx 0.2$ nm, parallel and perpendicular to the CuO_2 -layer [6]. From this it follows that the influence of structure inhomogeneity and thus the suppression of phase coherence should be in general far more important in HTSCs than in LTSCs.

Actually the HTSC films or bulk samples are always disordered and inhomogeneous to some extent. For example, in polycrystalline samples the regions of grain boundaries are highly disordered. These regions can be not only non-superconductive, but dielectric as well [7,8]. In fact, polycrystalline samples are granular metals in which superconducting coherence between the grains can be established by Josephson coupling. Beside the granularity, chemical-composition inhomogeneity is quite common in HTSCs. The influence of this type of inhomogeneity on superconductivity can be rather strong since charge carrier density of HTSCs depends strongly on chemical composition [5,6]. The composition disorder can contribute to destroying of superconducting phase coherence in the same fashion as the granularity. In most cases the inhomogeneous distribution of oxygen leads to this type

of disorder. Two main sources for oxygen inhomogeneity can be distinguished: extrinsic and intrinsic. Extrinsic source is due to various technological factors of sample preparation. The intrinsic one is connected with phase separation of HTSCs on two phases with different oxygen and hence charge carrier concentration [9].

It is clear from the aforesaid that to a good approximation the two main types of disorder, which are essential for superconductivity, can be distinguished. The first of them is disorder associated with perturbations of crystal lattice on the atomic scale (impurities, vacancies, and the like). This type of disorder is often called microscopic. It can be responsible for electron localization and other phenomena [2–4] which affect the superconducting order parameter. The second type of disorder is associated with structural inhomogeneity of superconductor (granular structure, phase separation, inhomogeneity due to technological reasons). The disorder scale in this case is much more than interatomic distances (at least, more than, say, 10-100 nm) and hence, this disorder can be called macroscopic. The macroscopic disorder affects mainly the superconducting phase coherence. In experimental studies it is desirable to separate the effects of microscopic and macroscopic disorder or, at least, to be aware of the possible joint action of them in the case where such separation is difficult. Ignoring this point could lead to serious errors in interpretation of experimental results or to total their misunderstanding.

In study of disorder effects in HTSCs it is important to use reliable methods of controllable disordering. Ideally, it is desirable to "tune" disorder while keeping other parameters fixed. At present, the main method which is expected to be somewhat close to such ideal is irradiation of superconductor with fast (charged or uncharged) particles or with high-energy photons (γ -rays). By appropriate choice of particles and their energy the irradiation would be expected to produce only the microscopic disorder (vacancies and interstitials), although in the HTSCs a possibility of inducing of compositional disorder must be always taken into account.

In this communication we present some new results of investigation of influence of γ -irradiation on the critical temperature of bulk polycrystalline $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ (YBCO). The

disordering of HTSCs with γ -rays was used rather often in previous experiments, especially in the first years after discovery of HTSCs [10–17]. Such type of investigations could have an applied importance in the case of possible use of HTSCs in environments of nuclear reactors or space stations. The fundamental importance of experiments of this sort is also beyond question.

It is known that γ -rays produce ionization in solids [18,19]. In metals, ionization produced by radiation is very rapidly neutralized by the conduction electrons [19]. Beside this, γ -rays produce displaced atoms in solid, namely, vacancy-interstitial pairs (Frenkel defects) of small separation, randomly distributed through the lattice. Interaction of γ -rays with matter, which leads to atomic displacements, occurs principally by means of three mechanisms: the photoelectric effect, the Compton effect, and pair production [18,19]. In all three processes electrons are ejected with energy comparable with the original γ -ray energy, and thus γ -ray irradiation inevitably causes a substance to be internally bombarded by fairly energetic electrons [19]. At γ -ray energy of a few MeV, the dominant contribution to displacement production comes from Compton effect.

When compared with other irradiation sources, γ -rays have one unquestionable advantage. Attenuation distances of γ -rays with energies of few MeV are order of a few centimeters. This enables one to investigate bulk samples of HTSCs. By contrast, penetration distances for irradiation with particles or ions are small. In this case it is possible to study the disorder effects quite properly only in rather thin films of HTSCs. Otherwise, it can not be excluded the implantation and doping effects as well as inhomogeneity of damage that plagues the interpretation of the experimental results.

A disadvantage of γ -rays is that the available monoenergetic radioactive sources give low γ -ray fluxes. Taking into account the effective cross section for atomic displacement through the Compton mechanism [19] one would not expect any significant changes in the conductivity of typical metals, like copper. Indeed, a typical dose of γ -ray irradiation is about 1×10^{17} photons/cm². For this dose, the number of displacements per atom (dpa) for copper is about 10^{-8} [19,20]. The calculated increase in resistivity of copper due to 1% of

point defects (that is for 0.01 dpa) is about $1 \mu\Omega \text{ cm}$ [19–21]. From this it is apparent that the fraction of displaced atoms, which can be produced through the Compton mechanism in a convenient irradiation time, should not induce any noticeable resistance variations in good metals. However, in poor conductors with low charge density, such as semiconductors, γ -rays can strongly influence the conductivity through the carrier removal [22,23].

Charge-carrier density in optimally doped HTSCs (such as YBCO) is usually about $5 \times 10^{21} \text{ cm}^{-3}$ [3], that is well below that of good metals. This density is not however low enough to expect some significant influence of γ -ray irradiation on conductivity and order parameter of HTSCs, and hence, on their T_c . In spite of this, in some known experiments a quite appreciable effect of γ -irradiation on T_c and resistivity of YBCO was revealed. The maximal decrease in T_c was found to be about 2K by high doses $\Phi \simeq 1000 \text{ MR}$ [11,14]. In general, the published experimental results [10–17] about the effect of γ -irradiation on YBCO are quite contradictory (all of them concern the optimally doped YBCO with T_c above 90 K). For example, in contrast to Ref. [11,14], in some other investigations no change in T_c was found at all up to doses about 1000 MR [13], or found to be much less than 1 K [16,17]. The results about γ -ray effect in resistivity are even more conflicting. It is possible to find among them such extremal cases: a) No influence at all up to dose $\Phi \simeq 1000 \text{ MR}$ [13]; b) A nearly tenfold increase in resistivity at $\Phi \simeq 150 \text{ MR}$ [17].

The above-mentioned relevant γ -ray papers [10–17] just present experimental results without much (or any) consideration of possible mechanisms of γ -ray influence on conductivity and T_c of HTSCs, or presentation of general view on such influence. In none of them the degree of radiation damage (the value of dpa) has been estimated that severely hinders the understanding and interpretation of the results. It may be inferred, therefore, that the understanding of γ -ray influence on HTSCs is far from completion and that further experimental and theoretical investigations of this matter are necessary.

In this paper, we report investigation of the effect of γ -rays on T_c and resistive transition to superconducting state in bulk polycrystalline sample of optimally doped YBCO. We have observed non-monotonic behavior of T_c with increasing irradiation dose Φ (up to about 220

MR): T_c decreases at low doses ($\Phi \leq 50$ MR) approximately by 2 K and then rises, forming a minimum. Quite unexpected, at highest doses ($\Phi \geq 120$ MR) T_c value goes clearly down again. The temperature width, δT_c , of resistive superconducting transition increases rather sharp with dose in the range $\Phi \leq 75$ MR and somewhat drops at higher dose. We believe that this interesting effect is revealed for the first time. Unlike previous works [10–17], we have calculated cross sections for the displacement of different kinds of lattice atoms in YBCO by γ -rays due to the Compton process. To our knowledge, nobody has done it before for HTSCs. This enables us to estimate the possible dpa value and has facilitated the interpretation of results.

On the strength of the obtained results and those of previous investigations, together with the results of radiation damage calculation, we come to conclusion that for commonly used doses (up to $\Phi \simeq 1000$ MR) γ -rays should not produce any substantial influence on superconducting properties and conductivity of single-crystal HTSCs. In polycrystalline samples however this influence can be fairly strong. These samples, as was mentioned above, are in fact granular metals which consist of metallic grains separated by dielectric interlayers. In the HTSCs the regions of grain boundaries, and near environments of them, are strongly depleted with charge carriers [7,8] and thus should be very sensitive to γ -rays and radiation of any other kind. For this reason the conductivity and T_c in polycrystalline HTSCs can be markedly affected by γ -rays even at commonly used not very high doses. This is the main conclusion of our paper. Based on this it is possible to understand, at least qualitatively, the sharp distinction between the known published results about γ -ray influence on YBCO. In this paper, the possible mechanisms of impact of radiation-damage in grain boundary regions upon the conductivity and T_c in YBCO are considered. Beside the atomic displacements, the probable effects of atom ionization in grain boundary regions by γ -rays are speculatively discussed.

II. SAMPLE AND EXPERIMENT

For sample preparing the conventional solid-state reaction method was used. Fine powders of Y_2O_3 , BaO and CuO were mixed in alumina mortar in the composition of $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$. Then the mixture was pressed to pellet at pressure about 100 MPa. This pellet was heated at $T \approx 930^\circ\text{C}$ in air and then slowly cooled down. From the pellet a $3.1 \times 6.3 \times 22 \text{ mm}^3$ bar was cut. The oxygen content in sample was estimated to be about 6.9 ($\delta \approx 0.1$). The sample was polycrystalline with rather large grain size (about $12 \mu\text{m}$). Density of sample was 5.2 g/cm^3 , that comprises about 80% of the expected density for this compound. The 20% difference can be attributed to an occurrence of small voids and pores that is quite usual for polycrystalline samples.

Irradiation was carried out using ^{60}Co γ -ray source at room temperature in air at different doses up to $\Phi \approx 220 \text{ MR}$. This isotope emits the equal amounts of photons with energies 1.17 MeV and 1.33 MeV. The dose rate of used source was $6.34 \times 10^4 \text{ R/h}$. The temperature dependences of resistance $R(T)$ were measured by standard four-probe method with a direct measuring current 10 mA. The accuracy of temperature measurements was estimated to be about 0.1 K.

III. RADIATION-DAMAGE CALCULATION

In experimental investigations of radiation effects in solids it is imperative to realize the degree of disorder produced by irradiation in objects studied. Without such knowledge, adequate understanding and interpretation of results obtained is impossible. In many cases such ignorance can lead to wrong conclusions. For this reason, calculations of possible radiation damage, primarily the dpa values, become nowadays an integral part of the most of radiation-effect investigations. For example, at ion irradiation studies the well-known TRIM simulation program [24] is widely used. The surprising thing is that one cannot find even rough estimates of dpa in the known studies of γ -ray effect in YBCO [10–17]. This type

of calculations is rather cumbersome and may be for this reason they had not been done in the above-mentioned studies. The principal concepts of such calculations are however quite established [18,19,22,23] and therefore the estimation of dpa or concentration of point defects induced by γ -rays can be done without principal difficulties.

In this work we have calculated the cross sections for atomic displacements in YBCO by γ -rays due to the Compton process which is a main producer of energetic electrons at photon energy about 1 MeV [18,19]. Somewhat different versions of this type of calculation are presented in Ref. [19,22,23]. In this study the version of Ref. [19] was used. The number of atoms displaced in unit volume (cm^3) per second is expressed in Ref. [19] by

$$R_d^\beta = \int_0^{E_{max}} n_0 \sigma_d^\beta(E) \Phi_\beta(E) dE, \quad (2)$$

where n_0 is number of atoms per unit volume; $\sigma_d^\beta(E)$ is cross section for an atom to be displaced by an electron of energy E ; $\Phi_\beta(E)$ is flux density of ejected Compton electrons per cm^2/sec , at energy E , per unit range of energy; E_{max} is maximal energy of Compton electron, which is given by $E_{max} = 2E_\gamma/(1 + 2E_\gamma)$ with E_γ being photon energy in monoenergetic γ -ray flux. The Eq. (2) can be written in more detail:

$$R_d^\beta = \Phi_\gamma n_0^2 \int_0^{E_{max}} dE \sigma_d^\beta(E) (-dE/dx)^{-1} \int_E^{E_{max}} \sigma_c(E') dE', \quad (3)$$

where Φ_γ is γ -ray flux per cm^2/sec , $\sigma_c(E')$ is cross section per atom for the production of a Compton electron at energy E . This is given by the formula [18]

$$\sigma_c(\epsilon) = \sigma_0 \left\{ \frac{1}{1 - \epsilon} + 1 - \epsilon + \frac{\epsilon}{\gamma^2(1 - \epsilon)} \left[\frac{\epsilon}{1 - \epsilon} - 2\gamma \right] \right\}, \quad (4)$$

where $\epsilon = E/E_\gamma$, $\gamma = E_\gamma/mc^2$, and $\sigma_0 = \pi r_0^2 Z_2 mc^2/E_\gamma^2$. Here e and m are electronic charge and mass, respectively, c is velocity of light, $r_0 = e^2/mc^2$, and Z_2 is the atomic number. The energy loss per cm of electron path, $-dE/dx$, is given by [19]

$$-dE/dx = a \left[\left(1 + E/mc^2 \right) / E \right] \quad (5)$$

where $a = 2\pi e^4 n_0 Z_2 L$, $L \approx 10$.

The cross section $\sigma_d^\beta(E)$ in Eqs. (2) and (3) for an atom to be displaced by an electron of energy E depends essentially on the specific value of the threshold energy E_d . It is assumed [19,21] that an atom is always displaced from its lattice site when it receives energy greater than E_d and is never displaced at lower energy. Therefore, it should be put down $\sigma_d^\beta(E) = 0$ in Eq. (3) if $E < E_d$. For the greater values of E we have used the known McKinley-Feshbach formula [19,25] to calculate $\sigma_d^\beta(E)$:

$$\sigma_d^\beta(E) = \frac{\pi}{4} b^2 \left[\left(\frac{T_m}{E_d} - 1 \right) - \beta^2 \ln \frac{T_m}{E_d} + \pi \alpha \beta \left\{ 2 \left[\left(\frac{T_m}{E_d} \right)^{1/2} - 1 \right] - \ln \frac{T_m}{E_d} \right\} \right] \quad (6)$$

where $(\pi/4)b^2 = \pi Z_2 r_0^2 (1 - \beta^2)/\beta^4$; $\beta = v/c$ that is the ratio of electron and light velocities for which the relation $\beta^2 = E(E + 2)/(E + 1)^2$ is true if E is taken in the units of mc^2 ; $\alpha \approx Z_2/137$, and T_m is the maximum energy which can be transferred in a collision by an electron of kinetic energy E :

$$T_m = \frac{2(E + 2mc^2)}{M_2 c^2} E, \quad (7)$$

where M_2 is the target atomic mass.

Some additional comments about the McKinley-Feshbach formula are necessary. It is assumed that it is accurate to one percent for Z_2 up to 40 [23]. Atomic numbers of elements in YBCO are 8(O), 29 (Cu), 39 (Y), and 56 (Ba). Therefore, an error more than one percent should be expected only for Ba atoms. But displacement cross section for heavy atoms is usually much less than for light ones, and thus, contribution from heavy atoms to total dpa should be rather small. For this reason we did not expect a significant error with the McKinley-Feshbach formula. This was justified by our calculations which are presented below.

If the struck atom has large enough energy it can cause secondary displacements [20] which can also be taken into account at calculation of numbers of the displaced atoms due to γ -rays [23]. It is easy to see however that at electron energy about 1 MeV the values of T_m given by Eq. (7) are quite small and therefore this effect can be neglected. Nonetheless, we have done cascade calculations following the recommendations of Refs. [20,23] and have found that primary displacement cross sections differ from these of total displacement cross

sections only by few percents. Although we will present below the total displacement cross sections, it should be kept in mind that they differ very slightly from those of obtained using Eqs. (4)–(7).

The calculated values of the effective cross section for atomic displacement by γ -rays from ^{60}Co source through the Compton effect, $\sigma_c^\gamma = R_d^\beta / (\Phi_\gamma n_0)$, at different values of threshold energy E_d for ions in YBCO are given in Table I. The values of σ_c^γ presented in this Table are the weighted averages for photons with energies 1.17 MeV and 1.33 MeV which are emitted by ^{60}Co source. The values of n_0 for different ions at calculation of σ_c^γ were just partial ion densities for compound $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ deduced taking into account the compact YBCO mass density which is about 6.4 g/cm³. It can be seen from Table I that the σ_c^γ values depend crucially on threshold energy E_d . It is worth noting also that the σ_c^γ values for heavy Ba ions are the least as compared with other ions, as expected. The data of Table I will be used below for estimation of possible dpa values in studied YBCO after γ -irradiation.

IV. RESULTS AND DISCUSSION

The temperature dependence of sample resistivity $\rho(T)$ before γ -irradiation is presented in Fig. 1. The dependence is quite common for optimally doped YBCO: it is linear above the superconducting resistive transition up to room temperature, T_c value is about 93 K. We have defined experimental T_c to be the temperature at which normal resistance R_n is halved. The dependences $R_n(T)$ in the range of resistive transition have been obtained by extrapolation of linear $R(T)$ dependence to this region. We have used the temperature T_{cz} at which resistance goes to zero as a second characteristic of resistive transition. In fact, T_{cz} is the end point of resistive transition to superconducting state, and is an essential characteristic which should be taken into account for granular or inhomogeneous superconductors. The difference in T_c and T_{cz} , $\delta T_c = T_c - T_{cz}$, is some quite definite measure of the width of resistive transition.

In early days of HTSC investigations (and quite often up to date) the experimental T_c

was defined as the temperature T_{cb} at the onset of the superconducting transition. Although this is also quite essential characteristic of resistive transition, it can be evaluated with much less precision than T_c or T_{cz} . For this reason only the observed changes in T_c and T_{cz} with γ -ray dose will be considered below.

The $\rho(T)$ curves for different γ -ray doses Φ in the temperature range of superconducting transition are presented in Fig. 2. It can be seen that T_c depends on Φ in a non-monotonic way. More clearly this is seen in Fig. 3 where the changes in T_c and T_{cz} with γ -ray dose are shown. It follows from the Figure that T_c decreases at low dose ($\Phi \leq 50$ MR) by ≈ 2 K and then rises, forming a minimum. At higher dose ($\Phi \geq 120$ MR) T_c value goes clearly down again. The zero-resistance temperature T_{cz} has been changing with γ -ray dose in the nearly same way as T_c , but with greater amplitude: the initial decrease in T_{cz} is about 4 K. The magnitude of δT_c (which characterizes the width of resistive transition and, hence, the sample inhomogeneity) increases with dose in the range $\Phi \leq 75$ MR and somewhat drops at higher doses (Fig. 4).

The observed initial T_c decrease with γ -ray dose (Fig. 3) corresponds to some of previous studies [11,14], but the general picture of non-monotonic dependence of T_c on radiation dose looks like a surprising thing. To our knowledge such behavior of T_c in HTSC with γ -ray dose is found for the first time. A somewhat (or partially) similar non-monotonic behavior has been seen previously [12] in γ -irradiated YBCO-related compound $Y_{0.9}Sm_{0.1}Ba_2Cu_3O_{7-\delta}$, but for the onset temperature T_{cb} only. As this took place, the zero-resistance temperature T_{cz} had not manifested any marked influence of γ -irradiation [12]. The resistive-transition curves shown in Ref. [12] are rather steep (no large difference between the T_c and T_{cz} values). At the same time the reported values of the onset temperature T_{cb} (about 140 K) appear to be too high for YBCO-related compounds (compare, for example, with the data of Ref. [13]). In our opinion in evaluating the onset temperature T_{cb} from $R(T)$ curves the significant error is possible. Since an employed procedure for evaluating of the T_{cb} values has not been outlined in Ref. [12] one should take the T_{cb} values in it and the described non-monotonic behavior T_{cb} with γ -ray dose with some precaution.

The effect of γ -rays in the resistivity of sample studied was found to be appreciable only in the temperature range of rather broad resistive superconducting transition (Fig. 2). With increasing temperature away from T_c the γ -ray effect in resistivity falls off quickly. In particular, at $T \simeq 105$ K a mere 4% increase in resistivity by γ -rays was found, whereas above 200 K hardly any radiation effect in resistivity can be detected. This suggests that γ -rays affect primarily the superconducting properties of the sample studied while electron transport in normal state remains actually not affected.

In the course of explaining of the results obtained, it should be taken into account, first of all, that the sample studied is polycrystalline or, better to say, granular. Indeed, its resistivity in normal state just above the superconducting transition (about $2.5 \text{ m}\Omega \text{ cm}$, as can be seen in Figs. 1 and 2) is by a factor of 50 larger than that of the best quality optimally doped YBCO single-crystals (about $50 \text{ }\mu\Omega \text{ cm}$ [26,27]). The increased resistivity comes from grain boundaries, since regions of grain boundaries in HTSCs can be poor conductive and even dielectric [7,8].

The conductivity of granular metals in normal state is determined by tunneling of single-particle excitations (unpaired electrons) through the boundaries. In superconducting state the superconducting coherence between grains can be established by Josephson coupling. Although the sample studied is inhomogeneous (granular) its critical temperature $T_c = 93$ K corresponds to the highest T_c values in the good-quality YBCO single crystals [26,27]. Such situation is quite possible and understandable for inhomogeneous systems [2]. Granular metals usually have a spatial distribution of thicknesses of the poor-conductive or dielectric grain boundaries. This spread in the boundary thickness may be very important for transport properties, especially for dielectric grain boundaries because in this case the probability of tunneling is an exponential function of dielectric separation distance. From this follows that granular metals are actually percolating systems [28]. In such systems conductivity can be determined by the presence of optimal “chains” of grains with maximal probability of tunneling for adjacent pairs of grains forming the chain. The same type of percolation picture is true for a system of metallic grains with Josephson coupling between them (when grains

become superconducting at low enough temperature) [28]. The sample studied consists of rather large ($12\ \mu\text{m}$) grains with critical temperature T_c as high as that of in high-quality crystals. The global critical temperature of whole sample can be very close to this maximal value in the presence of good conducting optimal chains of grains with strong Josephson coupling (in utmost case, theoretically, even one such path will be enough to arrive to zero resistance).

Since conductivity of the granular metal is determined by both intragrain and intergrain transport properties, the influence of radiation damage in it should be considered separately for materials of grains and regions of grain boundaries. Let us consider at first a question: is the radiation damage induced by γ -ray in this study high enough to cause quite significant variations in resistivity and superconducting properties of material of grains. For this purpose, we have estimated the possible values of dpa in sample studied using the calculated in Sec. III effective cross sections for atomic displacement by γ -rays from ^{60}Co source through the Compton effect (Table I). It is easy to see that for the standard value of $E_d = 20\ \text{eV}$ the total dpa comprises very small value about 10^{-7} . There is experimental evidence that the displacement energy, E_d , for oxygen in CuO_2 planes in YBCO is close to $10\ \text{eV}$ [27]. In this case the dpa will be about 6×10^{-7} . From the general point of view (taking into account the rather high charge-carrier density in optimally doped YBCO) it should not be expected any significant variations in normal state resistivity and T_c in grains at such small radiation damage. Indeed, the known experimental studies of single-crystal HTSCs irradiated with electrons or ions show that an appreciable influence of disorder on resistivity and T_c can be detected only at dpa greater than $\simeq 10^{-3}$ [26,29,30].

It follows from the above consideration that with commonly used γ -ray doses ($\simeq 1000\ \text{MR}$) one should not expect any detectable variations in resistivity and T_c in fairly homogeneous single-crystal HTSC as well as in metallic grains of polycrystalline HTSC. For this reason we will not consider here the numerous theoretical models of disorder influence on superconducting properties of HTSCs (see Refs. [3,4] and references therein) which were developed for homogeneous superconductors. In this study we have not seen any marked

changes even in the normal state resistivity of the polycrystalline sample. But we observed the pronounced effect of γ -rays on T_c and the width of resistive transition (Figs. 2-4). This is undoubtedly connected with influence of γ -rays on poor conductive or dielectric regions of grain boundaries and, therefore, on the superconducting phase coherence between the grains.

One of the first impressive demonstration of radiation-induced destruction of phase coherence of the superconducting wave functions between grains in polycrystalline HTSC was demonstrated in Ref. [31] for optimally doped YBCO. They found that zero-resistance temperature T_{cz} was very sensitive to even low doses of irradiation with 500 keV oxygen. At the same time, the onset temperature T_{cb} declined much slowly. For doses, where T_{cz} was already close to zero, and furthermore, even, when insulating behavior of $R(T)$ was evident below 40 K, T_{cb} was close to 80 K (before irradiation T_{cb} was 97 K, and T_{cz} was 87 K). The authors of Ref. [31] have assumed that T_{cb} in this case reflects the behavior of intrinsic critical temperature of grains, which is not as sensitive to irradiation as that of the whole granular system.

In the years, following Ref. [31], the quality of HTSCs becomes much higher and the most of subsequent radiation studies were devoted to single-crystal (or, at least, nearly single crystal) HTSCs, which are usually far more homogeneous than polycrystalline samples, and for which, therefore, the phase coherence is not of decisive importance. It is certain, however, that not only single crystal HTSC products may be (or will be) used in advanced technology. Therefore inhomogeneity effect in superconductivity of these compound are still of fundamental and technological importance.

It can be said with confidence that the observed decrease in T_c and zero-resistance temperature T_{cz} combined with simultaneous increase in width of resistive transition δT_c in sample studied at low dose ($\Phi < 50$ MR) (Figs. 3 and 4) is quite expected for percolating granular system. Optimal current paths, which have ensured the measured T_c value about 93 K before irradiation, have sure some “weak” links. These are the grain boundaries, which are strongly enough depleted with charge carriers and, therefore, are sensitive even to such

small mean radiation damage as in this study (maximum 10^{-6} dpa). This leads to the observed decrease in the “global” T_c and increase in δT_c (Figs. 3 and 4).

The initial T_c drop (which appears to be explicable) is followed by an increase in T_c at higher dose $\Phi > 50$ MR (Fig. 3), and this is fairly surprising. This means that some concurrent mechanism, which causes an increase in T_c , comes into play. This mechanism shows itself only in the limited range of doses, since T_c decreases again in the range above $\Phi > 120$ MR (Fig. 3). Somehow this mechanism should be also associated with an impact of γ -rays on intergrain Josephson coupling. There are known some cases of superconductivity enhancement in polycrystalline HTSCs under irradiation. For example, an increase in T_c after low-dose irradiation with Si ions was observed in polycrystalline YBCO [32]. Explanations of the effect in Ref. [32] was not however connected with granular structure of sample. In Ref. [33] it was reported that γ -irradiation of granular $\text{Tl}_2\text{Ba}_2\text{Ca}_2\text{Cu}_3\text{O}_{10}$ at room temperature causes the increase of critical current. This is believed to be an indication of strengthening of the intergrain Josephson coupling under γ -ray influence.

The known features of interaction of γ -rays with solids [18,19] make it possible to suggest some mechanisms of T_c increasing in granular HTSCs at low enough γ -ray doses. In doing so two main points should be considered: (i) the nature of grain boundaries in HTSCs, (ii) the ionizing influence of γ -rays. From the literature data (see Refs. [7,8,34] and Refs. therein) it can be concluded that grain boundaries in HTSCs are disordered and oxygen deficient regions. A typical grain-boundary width in YBCO is about 2 nm [7,8] (what encompasses about 10 atomic distances). It is known that T_c of oxygen deficient YBCO compounds increases considerably with illumination of visible light. It was found that light leads to a change in doping (increasing in charge carrier density). This photoexcited state is persistent up to 250-270 K [35]. The photodoping effect is negligible for optimally doped YBCO. All existing models of the effect are based on the suggestion that sample illumination generates electron-hole pairs in the CuO_2 planes. Electrons are transferred to the CuO chains and trapped there, while holes remain mobile in the CuO_2 planes.

The most important effect of γ -rays in solids is ionization. In primary collision of γ -

quantum with an atom of solid the Compton electron and photon with lesser energy are produced. The energy of secondary photon is dissipated in causing further ionization. The same is true for the most of the energy of Compton electrons (only occasionally they displace atoms by elastic collision). Therefore, the number of ionized atoms at γ -irradiation is by several orders of magnitude larger than the number of displaced atoms. In this connection it must not be ruled out that effects like the above-mentioned photodoping by visible light [34,35] take place in γ -irradiated bulk samples as well. Of course, there is a significant difference in the energy of γ -ray and visible light photons. The visible light can eject only electrons from outer orbitals. These low energy electrons are trapped in nearby sites like CuO chains. By contrast, γ -quantum can struck out any electron from an atom. But in this case the ejected electrons have much higher energy and, therefore, can be brought far away from initial place. If electrons are ejected from CuO₂ planes in oxygen depleted grain boundary regions, this should increase the charge carrier density in the planes and, therefore, enhance the Josephson coupling between adjacent grains. If this takes place in some of “weak” links in optimal current path, this will result in increasing of measured T_c . Of course, the recombination of the electrons with excess holes should bring the charge carrier density in grain boundaries to an initial level. But some of these electrons should be sure trapped in remote defect places of crystal lattice like impurities, lattice distortions regions, including grain boundaries as well. If room temperature is not high enough for the electron-hole recombination of trapped electrons, this can lead to the observed effect of T_c enhancement in some intermediate dose range. At higher doses, however, influence of radiation defects (displaced atoms) in grain boundaries overpowers the ionizing effect of γ -rays that results in T_c decreasing. Needless to say that our explanation should not be considered as a conclusive. It needs an independent theoretical and experimental confirmation.

V. CONCLUSION

We have found non-monotonic behavior of T_c in optimally doped polycrystalline YBCO with increasing γ -ray irradiation dose. This result can be explained primarily by the influence of γ -rays on intergrain Josephson coupling. The two kinds of such influence are discussed. The first is the producing of displaced atoms, and the second is the ionizing influence of γ -rays.

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FIGURES

FIG. 1. Temperature dependence of the resistivity of non-irradiated $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ sample.

FIG. 2. The dependences $\rho(T)$ of sample studied in the temperature range of superconducting transition for different doses Φ .

FIG. 3. The changes in T_c and T_{cz} with γ -ray dose. The solid lines are guides to the eye.

FIG. 4. The change in $\delta T_c = T_c - T_{cz}$ with γ -ray dose. The solid line is a guide to the eye.

TABLES

TABLE I. Calculated values of the effective cross section for atomic displacement by γ -rays from ^{60}Co source through the Compton effect, $\sigma_c^\gamma = R_d^\beta/(\Phi_\gamma n_0)$, at different values of threshold energy E_d for ions in $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ (in units 10^{-24} cm^2). Additional comments to this table are given in the text of this paper.

Ion	E_d (eV)				
	10	15	20	25	30
Y	1.09	0.335	0.116	0.041	0.014
Ba	0.69	0.14	0.028	0.0045	≈ 0.001
Cu	1.29	0.479	0.208	0.097	0.047
O	1.13	0.58	0.349	0.23	0.16

Fig.1 to paper Belevtsev et.al

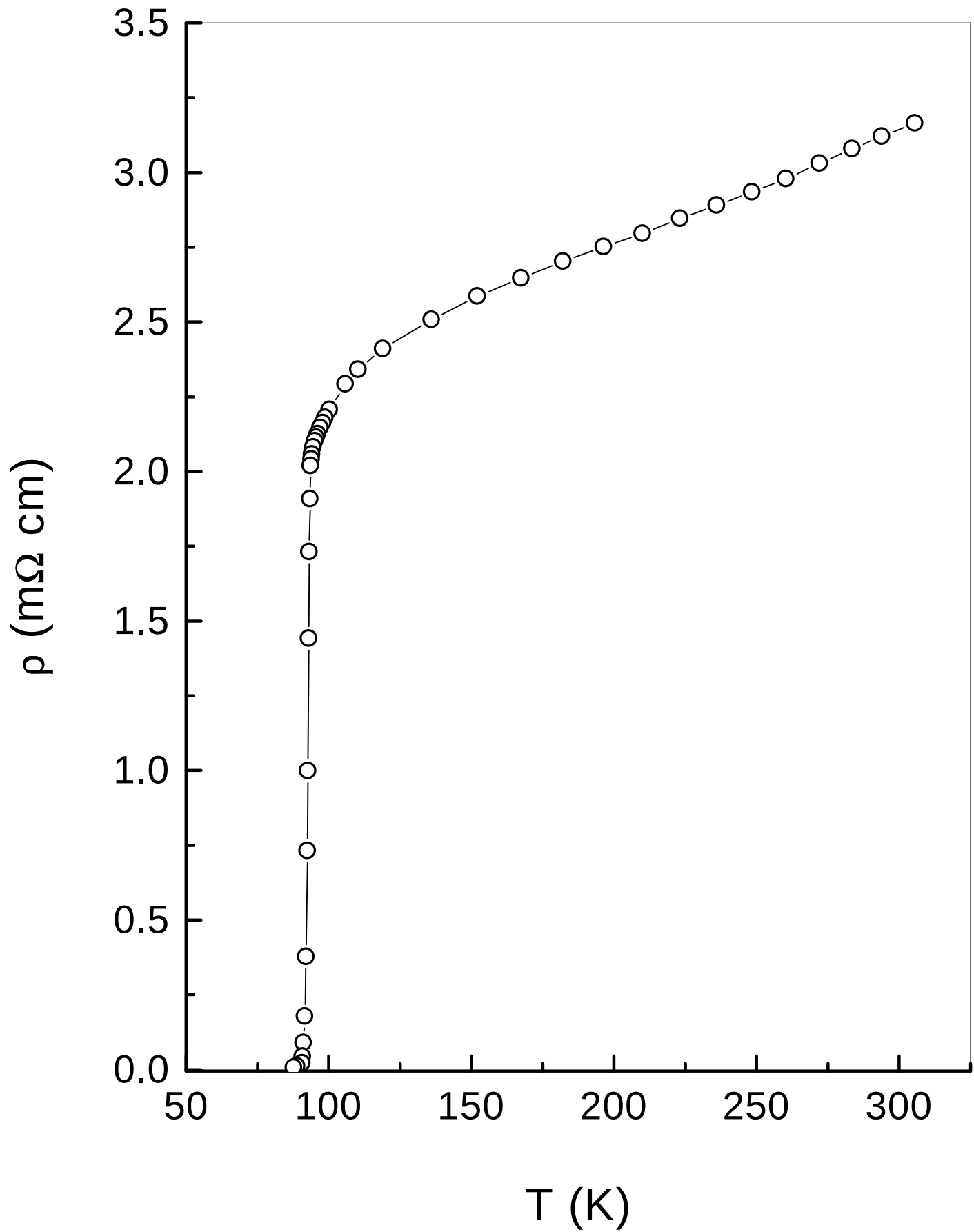


Fig.2 to paper Belevtsev et.al

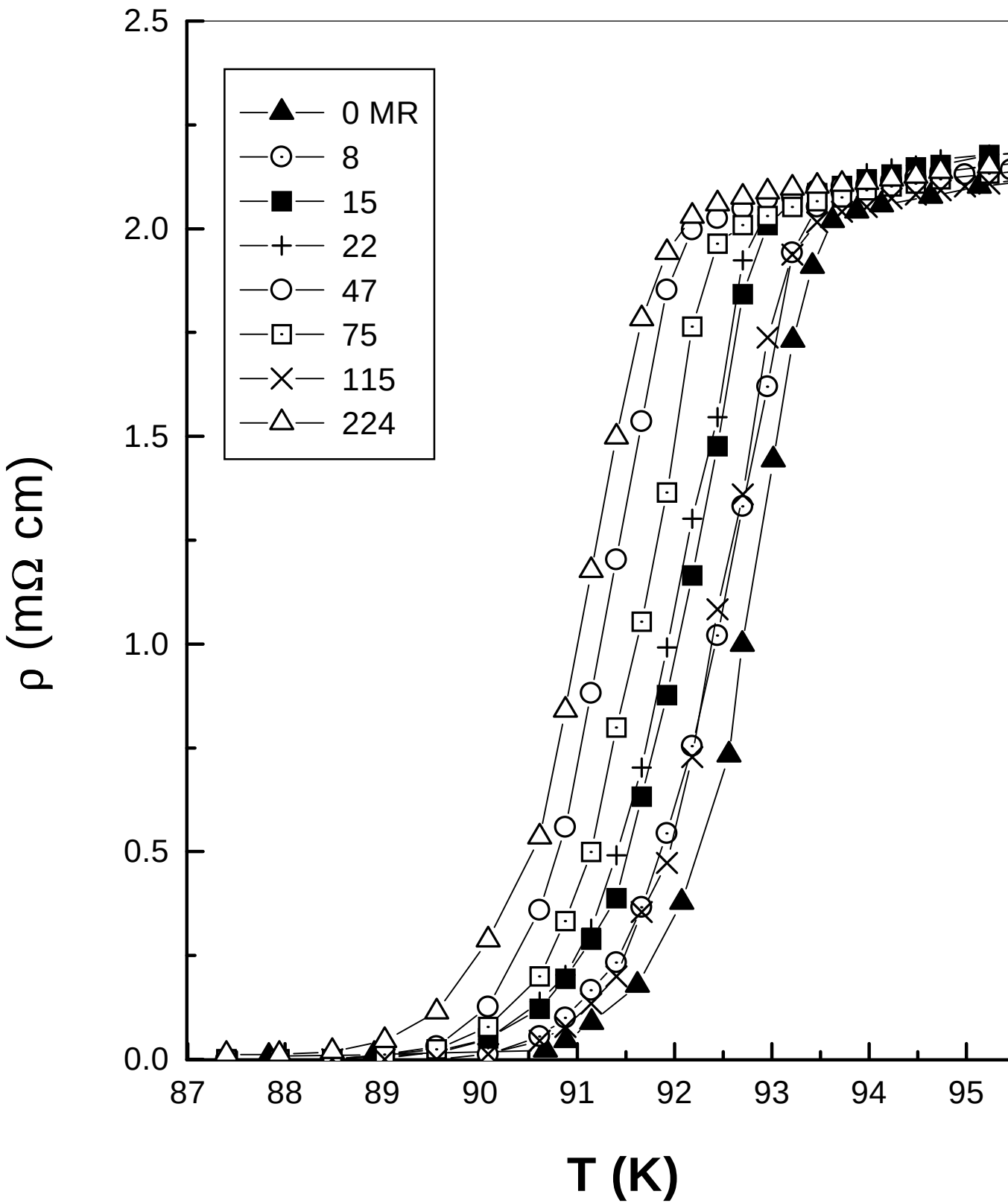


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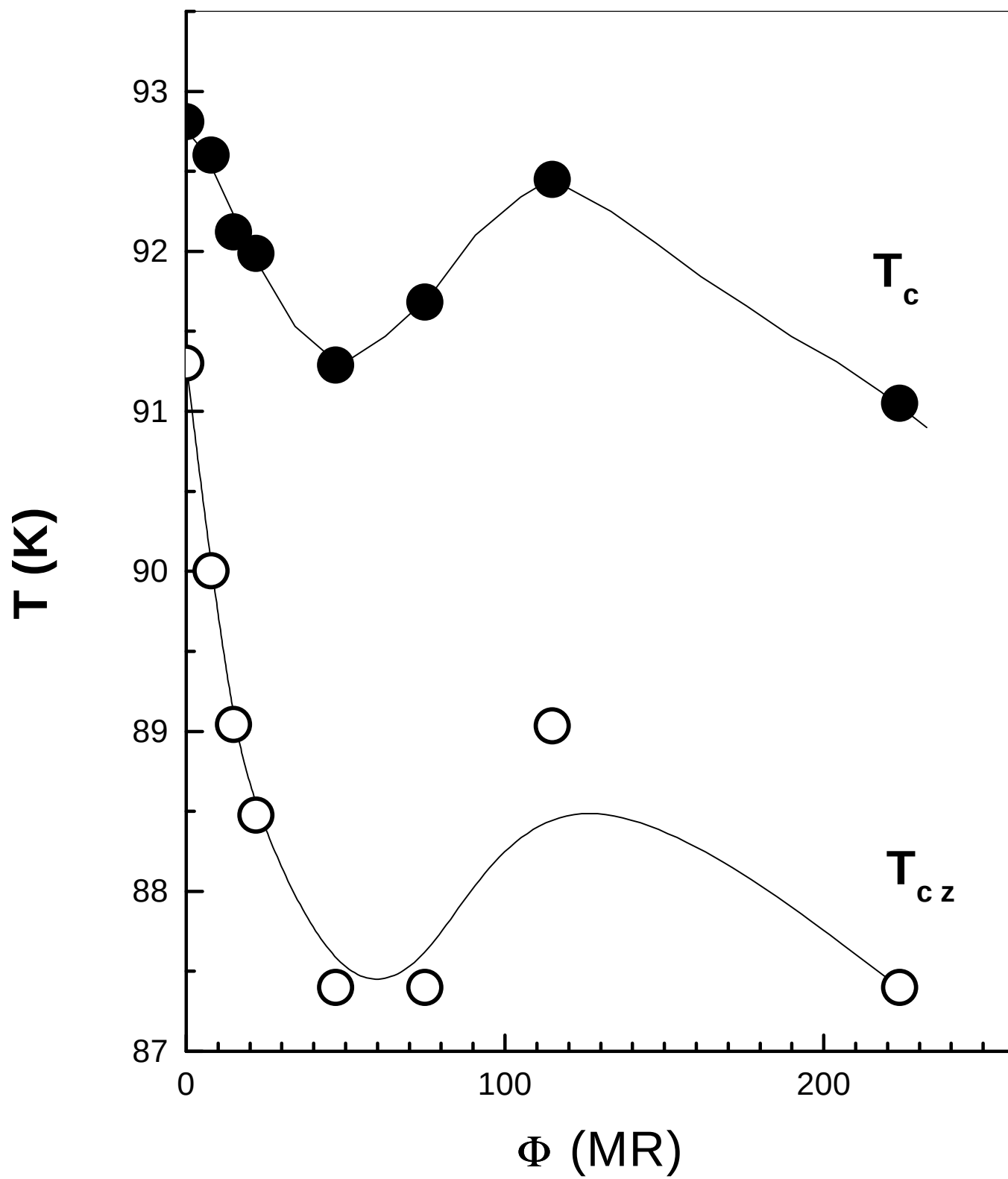


Fig.4 to paper Belevtsev et.al

